

AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection



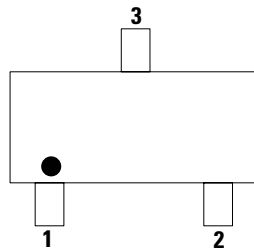
Description

The AQ48ETH-02HTG bidirectional TVS diode array utilizes a proprietary silicon avalanche technology to protect sensitive automotive electronics against ESD (electrostatic discharge) for 48V CAN/LIN Bus and other high-speed data network applications. Our robust AQ48ETH-02HTG bidirectional TVS diode array is designed to withstand the most challenging conditions. It can safely absorb repetitive 1000 times ESD strikes with ± 30 kV contact discharge as defined in ISO10605 (discharge storage capacitor $C = 150$ pF and discharge resistor $R = 330 \Omega$) without any performance degradation.

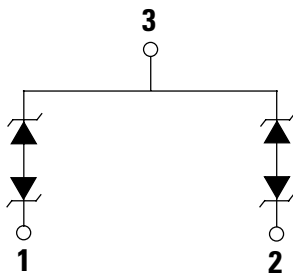
Features

- ESD, IEC 61000-4-2, ± 30 kV contact/air
- ESD, ISO10605 150 pF 330 Ω , ± 15 kV contact discharge at 1000 times
- ESD, ISO10605 330 pF 330 Ω , ± 30 kV contact/air
- EFT, IEC 61000-4-4, 40 A (5/50 ns)
- Maximum surge tolerance, IEC 61000-4-5 2nd edition, 3 A (8/20 μ s)
- Low leakage current of 0.1 μ A (max) at 48 V
- High trigger voltage of 100 V (Min) at V_{t1}
- Halogen free, lead free and RoHS compliant
- Moisture sensitivity level (MSL-1)
- AEC-Q101 qualified and PPAP capable
-

Pinout



Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Applications

- 48 V CAN/LIN Bus
- High Speed Data Networks

AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p = 8/20 \mu s$)	3	A
T_{OP}	Operating Temperature	-40 to 150	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

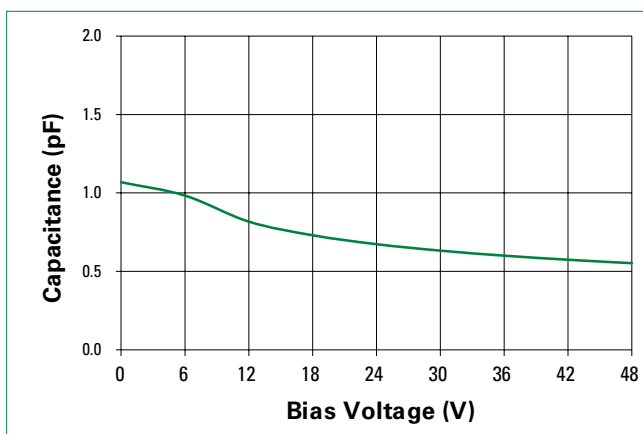
Electrical Characteristics ($T_{OP} = 25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}				48	V
Trigger Voltage ²	V_{t1}		100	160		V
Holding Voltage ²	V_h		28			V
Reverse Leakage Current	I_{LEAK}	$V_R = 48 V$, I/O to GND			100	nA
		$V_R = 70 V$, I/O to GND			100	nA
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100 ns$, I/O to GND		0.5		Ω
ESD Withstand Voltage	$V_{ESD}^{1,3}$	IEC 61000-4-2 (Contact Discharge)	± 30			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
		ISO 10605 (Contact Discharge)	± 30			kV
		ISO 10605 (Air Discharge)	± 30			kV
	$V_{ESD}^{1,4}$	ISO10605 (Contact Discharge)	± 15			kV
Diode Capacitance ¹	C_{IO-GND}	Reverse Bias = 0 V, $f = 1 MHz$, I/O to GND		1.6		pF

Note:

- Parameter is guaranteed by design and/or component characterization.
- Transmission Line Pulse (TLP) with 100 ns width, 0.2 ns rise time, and average window $t_1 = 70 ns$ to $t_2 = 90 ns$
- Device stressed with ten non-repetitive ESD pulses.
- Device stressed minimum number with >1000 contact discharges ESD pulses (OPEN Alliance specification)

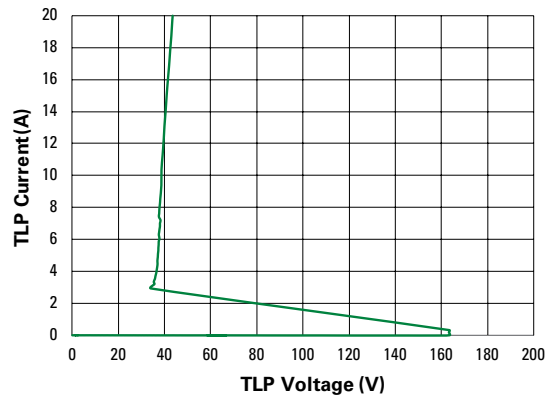
Capacitance vs. Reverse Bias



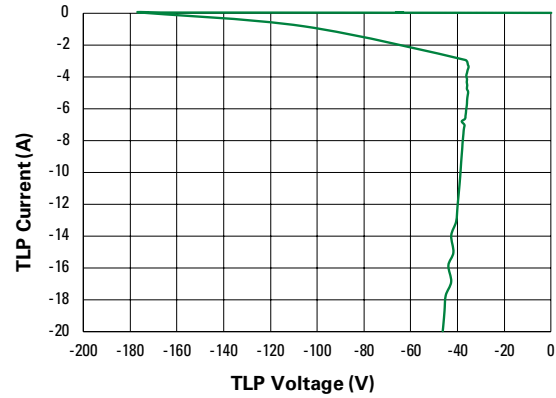
AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection

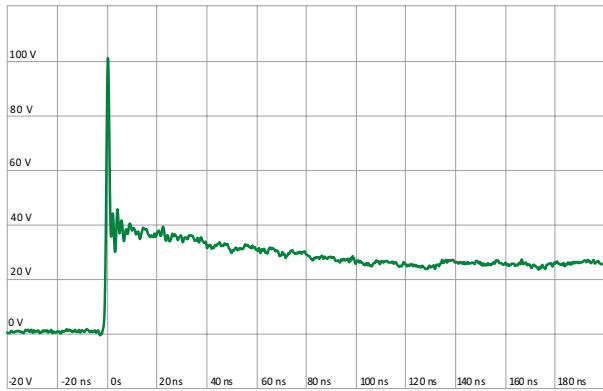
Positive Transmission Line Pulsing (TLP) Plot



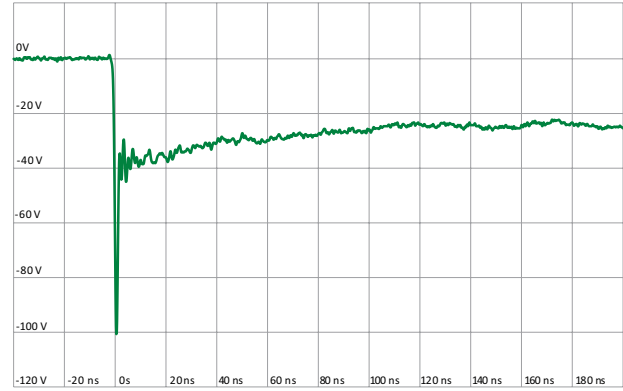
Negative Transmission Line Pulsing (TLP) Plot



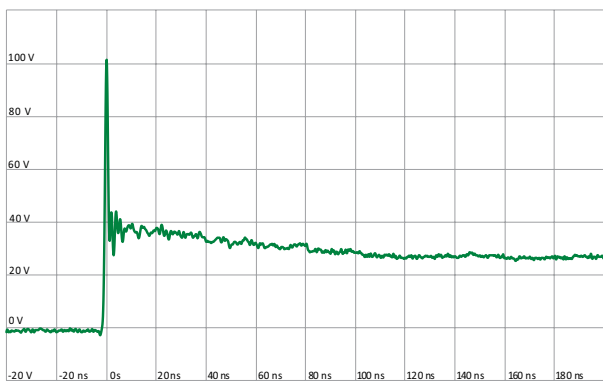
IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage



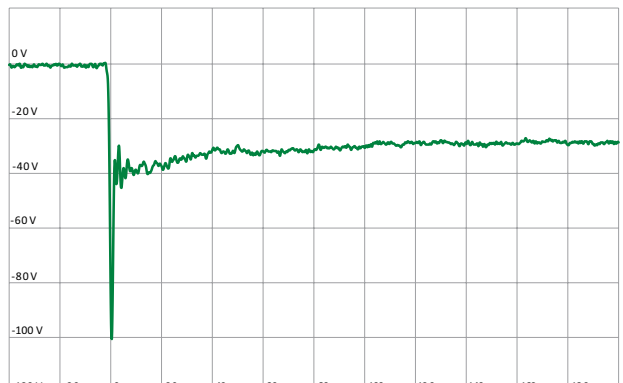
IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage



ISO10605 Contact Discharge Plot at +8 kV



ISO10605 Contact Discharge Plot at -8 kV

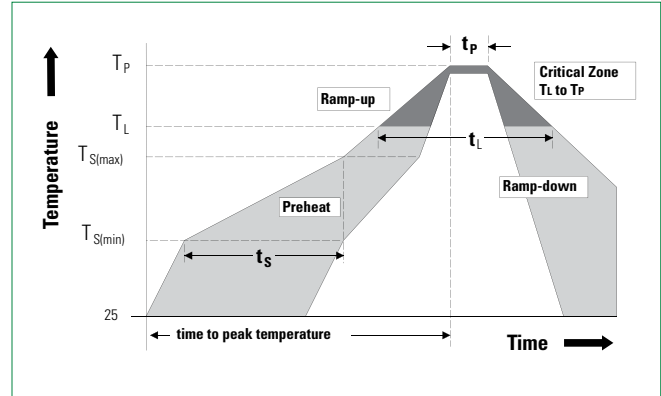


AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150 °C
	- Temperature Max ($T_{s(max)}$)	200 °C
	- Time (min to max) (t_s)	60 – 120 seconds
Average Ramp up Rate (Liquidus) Temp (T_L) to Peak		3 °C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3 °C/second max
Reflow	- Temperature (T_L) (Liquidus)	217 °C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5 °C of Actual Peak Temperature (t_p)		30 seconds
Ramp-down Rate		6 °C/second max
Time 25 °C to Peak Temperature (T_p)		8 minutes max
Do not exceed		260 °C



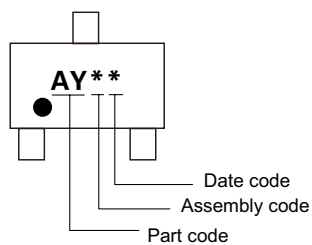
Ordering Information

Part Number	Package	Min. Order Qty.
AQ48ETH-02HTG	SOT23-3L	3000

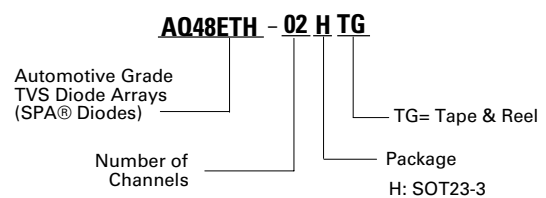
Product Characteristics

Lead Plating	Matte tin
Lead Material	Copper alloy
Lead Coplanarity	0.004 inches (0.102 mm)
Body Material	Molded compound
Flammability	UL recognized compound meeting flammability rating V-0

Part Marking System



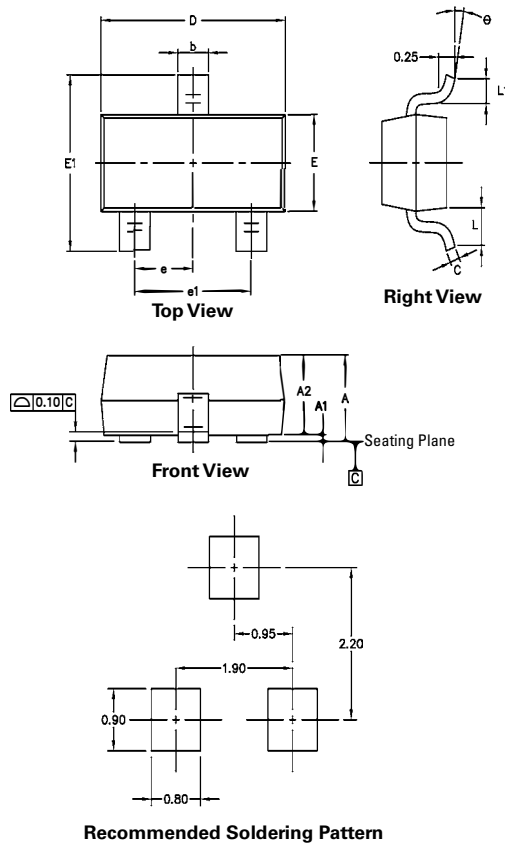
Part Numbering System



AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection

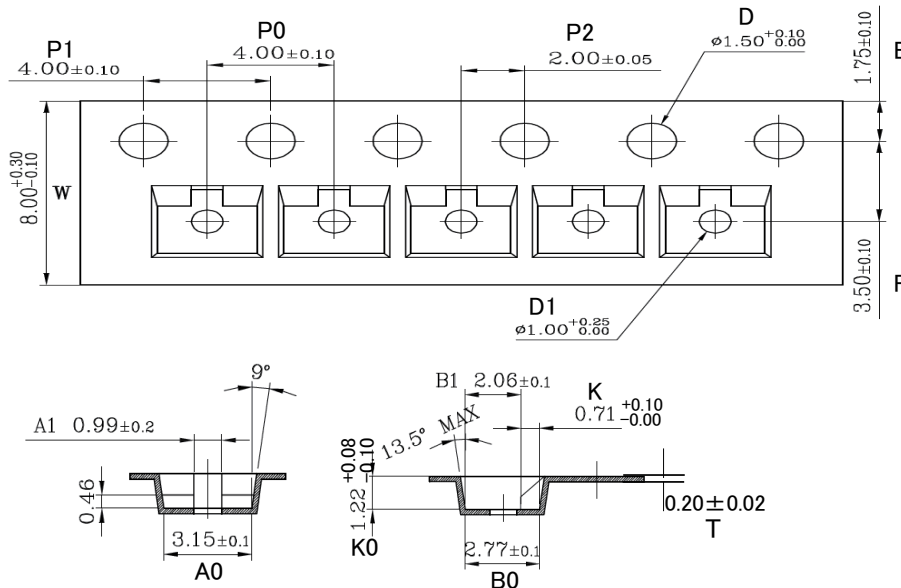
Package Dimensions - SOT23-3



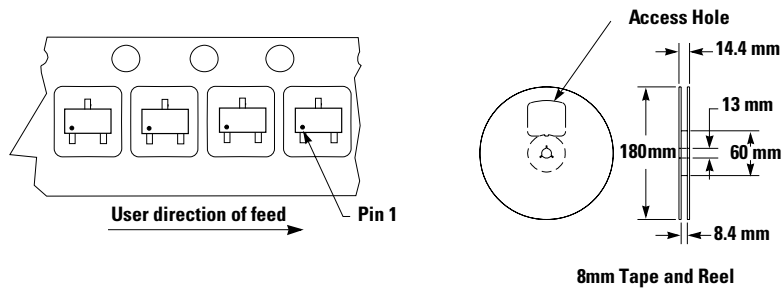
Package	SOT23-3			
Pins	3			
JEDEC	TO-236			
Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	0.880	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.880	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
C	0.080	0.200	0.003	0.008
D	2.800	3.040	0.110	0.120
E	1.200	1.400	0.047	0.055
E1	2.100	2.640	0.083	0.104
e	0.950 TYP		0.037 TYP	
e1	1.780	2.050	0.070	0.081
L	0.550 REF		0.022 REF	
L1	0.300	0.550	0.012	0.022
θ	0°	8°	0°	8°

AQ48ETH-02HTG

48 V, 1.6 pF, 30 kV, SOT23-3L, Bidirectional TVS Diode, Low Capacitance ESD Protection

Embossed Carrier Tape & Reel Specification – SOT23-3

Symbol	Millimeters	
	Min	Max
A0	3.05	3.25
A1	0.79	1.19
B0	2.67	2.87
B1	1.96	2.16
D	1.50	1.60
D1	1.00	1.25
F	3.40	3.60
E	1.65	1.85
W	7.90	8.30
P0	3.90	4.10
P1	3.90	4.10
P2	1.95	2.05
K	0.71	0.81
K0	1.12	1.30
T	0.18	0.22



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <http://www.littelfuse.com/disclaimer-electronics>.